



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

RECEIVED  
NOV 22 2002  
TC 2800 MAIL ROOM

re Application No. of

Hisao HAYASHI  
Application No. 09/808,957

Art Unit: 2822  
Examiner: M. Lewis

Filed: March 16, 2001

FOR: SUBSTRATE FOR INTEGRATING AND FORMING A THIN FILM  
SEMICONDUCTOR DEVICE THEREON (as amended)

REQUEST FOR RECONSIDERATION

Commissioner for Patents  
Washington, D.C. 20231

Sir:

In response to the non-final Office Action mailed on August  
20, 2002, please amend the above-identified application as  
follows:

11/27/2002 DBROWN 00000001 180013 09808957

01 FC:1202 126.00 CH  
IN THE TITLE

Please replace the title with the following title.

-- SUBSTRATE FOR INTEGRATING AND FORMING A THIN FILM  
SEMICONDUCTOR DEVICE THEREON --

IN THE SPECIFICATION

Please replace the paragraph beginning at page 5, line 20  
with the following rewritten paragraph.